

## Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	$I_D$
60V	2Ω@10V	100mA
	2.5Ω@4.5V	

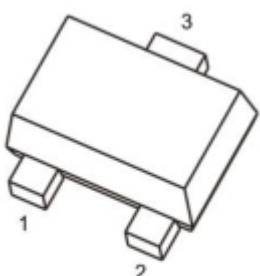
## Feature

- High density cell design for Low  $R_{DS(on)}$
- Voltage controlled small signal switch
- Rugged and reliable
- Parallel use is easy
- ESD protected

## Application

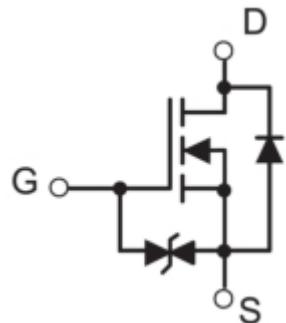
- Load Switch for Portable Devices
- Battery Switch

## Package

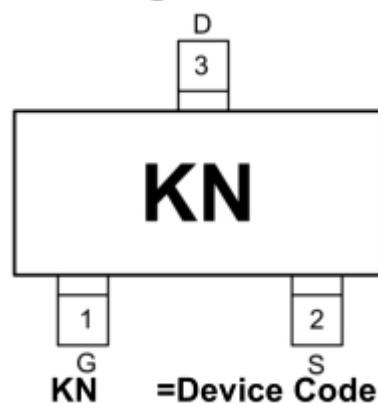


SOT-723

## Circuit diagram



## Marking



## Absolute maximum ratings

( $T_a=25^\circ\text{C}$  unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$V_{DS}$	60	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current	$I_D$	100	mA
Power Dissipation	$P_D$	0.15	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	833	$^\circ\text{C}/\text{W}$
Junction Temperature	$T_J$	150	$^\circ\text{C}$
Storage Temperature	$T_{STG}$	-55~+150	$^\circ\text{C}$

## Electrical characteristics

( $T_A=25^\circ\text{C}$ , unless otherwise noted)



ZL MOSFET

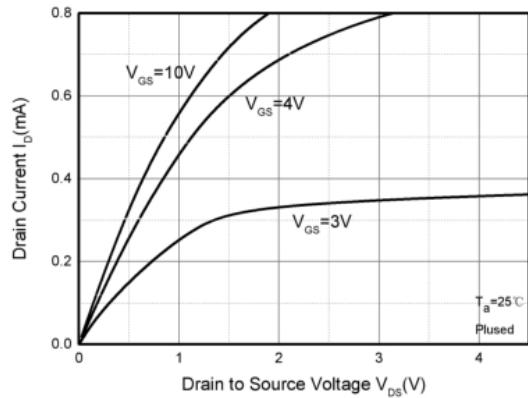
2SK3541

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
<b>Static Characteristics</b>						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	60			V
Zero gate voltage drain current	$I_{DSS}$	$V_{DS} = 48V, V_{GS} = 0V$			1	$\mu A$
Gate-body leakage current	$I_{GSS}$	$V_{GS} = \pm 20V, V_{DS} = 0V$			$\pm 5$	$\mu A$
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	0.7	1	1.45	V
Drain-source on-resistance	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 500mA$		2	5	$\Omega$
		$V_{GS} = 4.5V, I_D = 200mA$		2.5	8	
<b>Dynamic characteristics</b>						
Input Capacitance1)	$C_{iss}$	$V_{DS}=25V, V_{GS}=0V, f=1MHZ$		27		pF
Output Capacitance1)	$C_{oss}$			13		
Reverse Transfer Capacitance1)	$C_{rss}$			6		
<b>Switching Characteristics</b>						
Turn-on delay time	$t_{d(on)}$	$V_{DD}=30V, I_D=0.29A, V_{GEN}=10V, R_G=6\Omega$			5	ns
Rise time	$tr$				18	
Turn-off delay time	$t_{d(off)}$				36	
Fall time	$tf$				14	
<b>Source-Drain Diode Characteristics</b>						
Diode Forward voltage	$V_{SD}$	$V_{GS} = 0V, I_S=500mA$	0.5		1.4	V

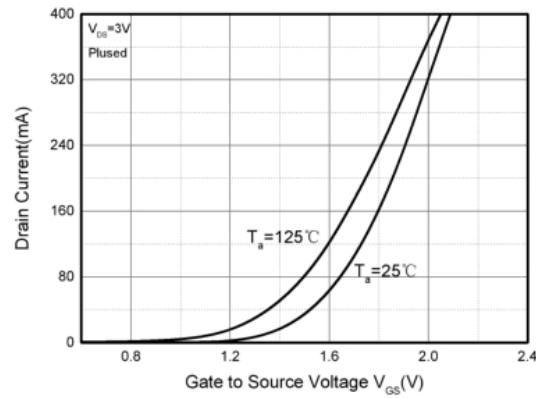
**Notes:**1. Pulse Test: Pulse Width  $\leq 300\mu s$ , Duty Cycle  $\leq 2\%$ .

2. These parameters have no way to verify.

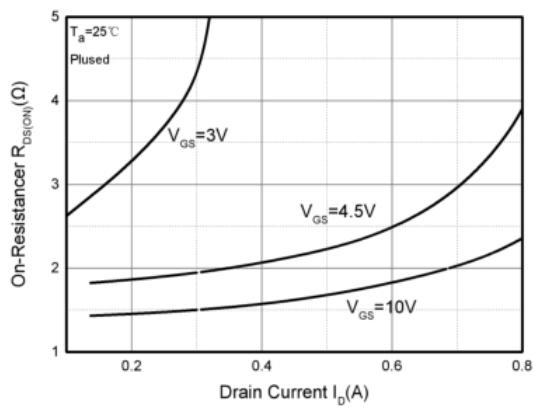
## Typical Characteristics



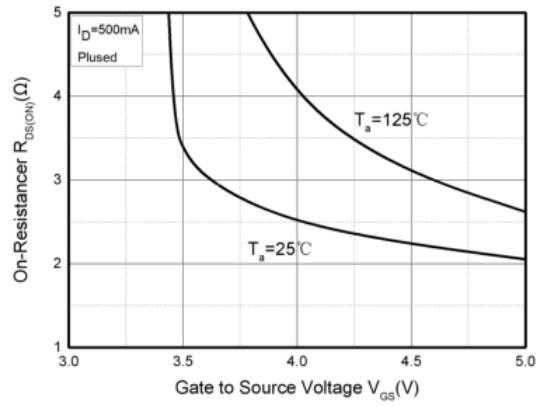
Output Characteristics



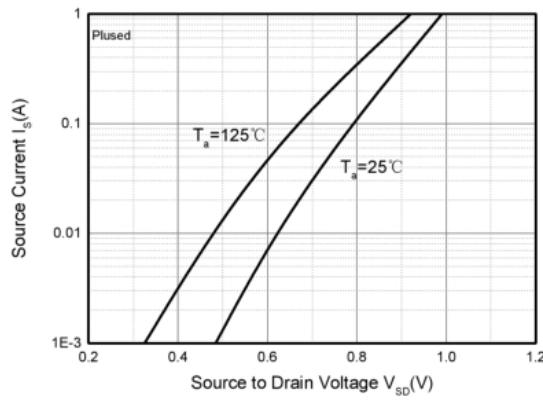
Transfer Characteristics



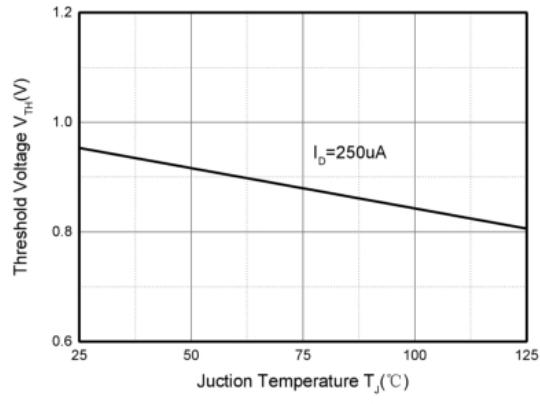
RDS(ON) — ID



RDS(ON) — VGS

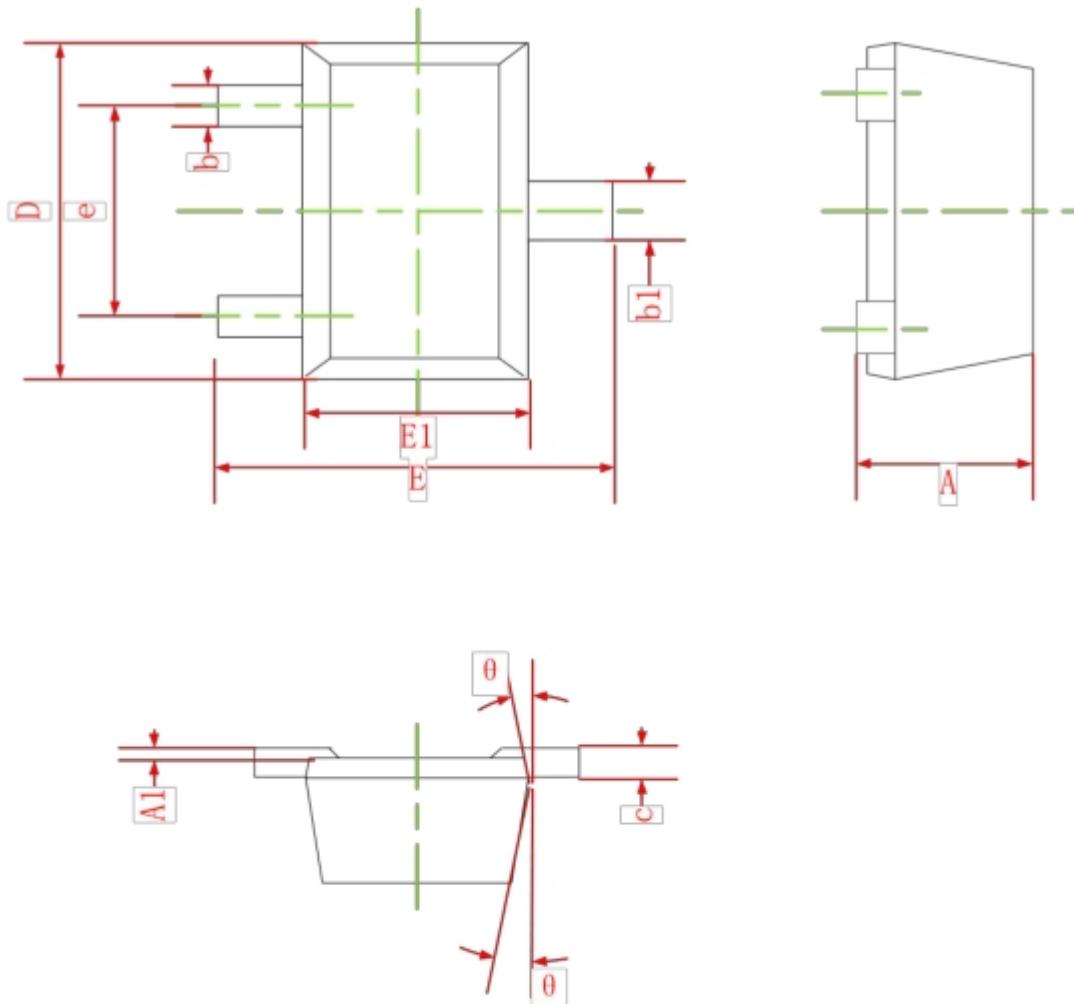


IS — VSD



Threshold Voltage

## SOT-723 Package Information



Symbol	Dimensions In Millimeters	
	Min.	Max.
A	0.430	0.500
A1	0.000	0.050
b	0.170	0.270
b1	0.270	0.370
c	0.080	0.150
D	1.150	1.250
E	1.150	1.250
E1	0.750	0.850
e	0.800TYP.	
θ	7° REF.	